



## DMN5L06DWK

#### Features

- Dual N-Channel MOSFET
- Low On-Resistance (1.0V Max)
- Very Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Ultra-Small Surface Mount Package
- ESD Protected up to 2kV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **DUAL N-CHANNEL ENHANCEMENT MODE MOSFET**

## **Mechanical Data**

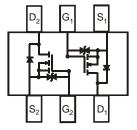
- Case: SOT363
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.006 grams (Approximate)





SOT363

Top View



Top View Internal Schematic

## Ordering Information (Note 4)

Part Number	Case	Packaging
DMN5L06DWK-7	SOT363	3,000/Tape & Reel

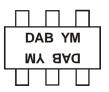
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



DAB = Marking Code YM = Date Code Marking Y = Year ex: T = 2006 M = Month ex: 9 = September

Date Code Key

Year	2006	2007	2008		2012	2013	2014	2015	2016	2017	2018	2019
Code	Т	U	V		Z	А	В	С	D	E	F	G
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec



### **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain Source Voltage	V <sub>DSS</sub>	50	V
Gate-Source Voltage	V <sub>GSS</sub>	±20	V
Drain Current Continuous Pulsed (Note 6)	ID	305 800	mA

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	250	mW
Thermal Resistance, Junction to Ambient	R <sub>θJA</sub>	500	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +150	°C

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							•	
Drain-Source Breakdown Voltage		BV <sub>DSS</sub>	50	_		V	$V_{GS} = 0V, I_D = 10\mu A$	
Zero Gate Voltage Drain Current	@ T <sub>C</sub> = +25°C	I <sub>DSS</sub>			60	nA	$V_{DS} = 50V, V_{GS} = 0V$	
					1	μA	$V_{GS} = \pm 12V, V_{DS} = 0V$	
Gate-Body Leakage		I <sub>GSS</sub>	—		500	nA	$V_{GS} = \pm 10V, V_{DS} = 0V$	
					50	nA	$V_{GS} = \pm 5V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)								
Gate Threshold Voltage		V <sub>GS(TH)</sub>	0.49	—	1.0	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
			—		3.0		$V_{GS} = 1.8V, I_D = 50mA$	
Static Drain-Source On-Resistance		R <sub>DS(ON)</sub>	—		2.5	Ω	$V_{GS} = 2.5V, I_D = 50mA$	
				—	2.0		$V_{GS} = 5.0V, I_D = 50mA$	
On-State Drain Current		I <sub>D(ON)</sub>	0.5	1.4	—	A	$V_{GS} = 10V, V_{DS} = 7.5V$	
Forward Transconductance		Y <sub>FS</sub>	200	—	—	mS	$V_{DS} = 10V, I_D = 0.2A$	
Source-Drain Diode Forward Voltage		V <sub>SD</sub>	0.5		1.4	V	$V_{GS} = 0V, I_{S} = 115mA$	
DYNAMIC CHARACTERISTICS (Note 8)					-			
Input Capacitance		CISS	_		50	pF		
Output Capacitance		C <sub>OSS</sub>	_		25	pF	$V_{DS} = 25V, V_{GS} = 0V$ f = 1.0MHz	
Reverse Transfer Capacitance		C <sub>RSS</sub>	_		5.0	pF		
Gate Resistance		$R_G$		65	—	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge		$Q_{G}$	_	0.4	_	nC		
Gate-Source Charge		Q <sub>GS</sub>	_	0.1	_	nC	$V_{GS} = 4.5V V_{DS} = 10V,$	
Gate-Drain Charge		$Q_{GD}$		0.1		nC	$I_{\rm D} = 0.25 {\rm A}$	
Turn-On Delay Time		t <sub>D(ON)</sub>		2.1		ns		
Turn-On Rise Time		t <sub>R</sub>		1.8		ns	$V_{DD} = 30V, V_{GS} = 10V,$	
Turn-Off Delay Time		t <sub>D(OFF)</sub>	_	14.4		ns	$R_{G} = 25\Omega, I_{D} = 0.2A$	
Turn-Off Fall Time		tF		8.4		ns	1	

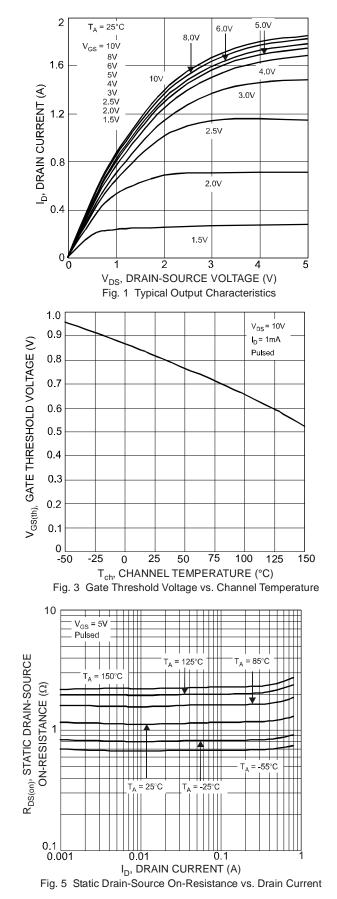
Notes: 5. Device mounted on FR-4 PCB.

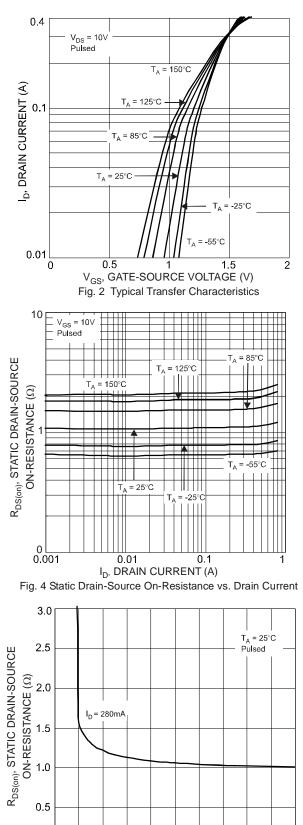
Pulse width ≤10μS, Duty Cycle ≤1%.
Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.



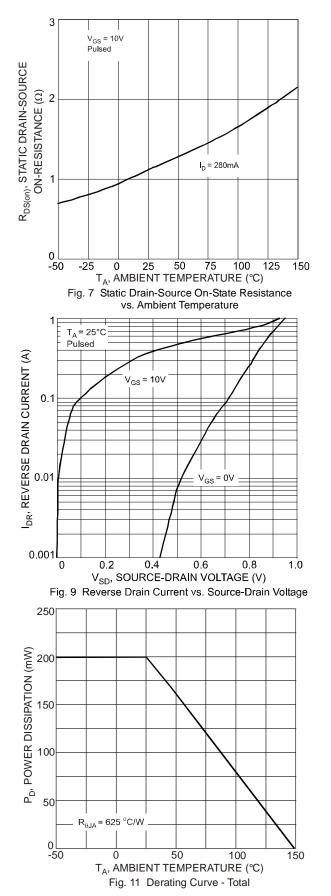
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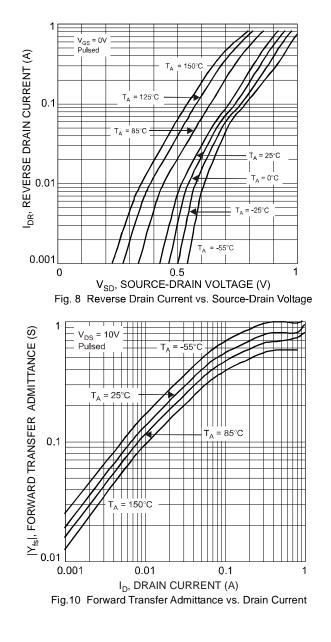








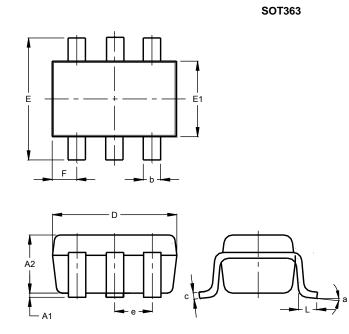






## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

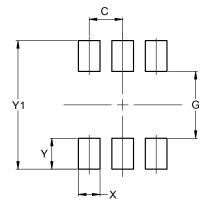


SOT363							
Dim	Min	Max	Тур				
A1	0.00	0.10	0.05				
A2	0.90	1.00	1.00				
b	0.10	0.30	0.25				
С	0.10	0.22	0.11				
D	1.80	2.20	2.15				
Е	2.00	2.20	2.10				
E1	1.15	1.35	1.30				
е	0.650 BSC						
F	0.40	0.45	0.425				
L	0.25	0.40	0.30				
а	0°	8°					
All Dimensions in mm							

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.





Dimensions	Value (in mm)			
С	0.650			
G	1.300			
Х	0.420			
Y	0.600			
Y1	2.500			



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